



# NPN POWER DARLINGTON TRANSISTORS

## D54H6D

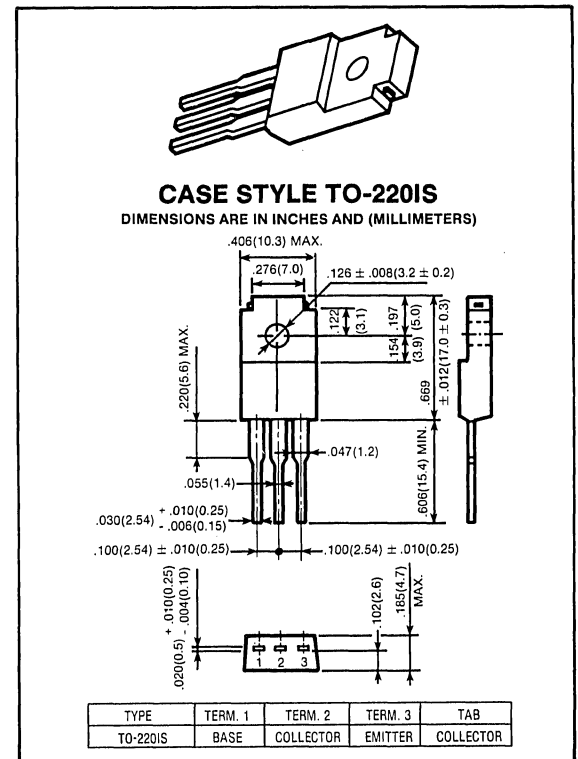
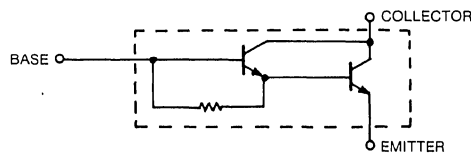
250 VOLTS  
6 AMP, 25 WATTS

Designed for igniter applications, high voltage switching applications.

### Features:

- High DC Current Gain:  
hFE = 2000 (Min.) (at VCE = 2V, IC = 2A)
- Isolated TO-220 package.

### EQUIVALENT CIRCUIT



maximum ratings ( $T_A = 25^\circ\text{C}$ ) (unless otherwise specified)

RATING	SYMBOL	D54H6D	UNITS
Collector-Emitter Voltage	$V_{CE0}$	250	Volts
Collector-Base Voltage	$V_{CB0}$	300	Volts
Emitter Base Voltage	$V_{EB0}$	5	Volts
Collector Current — Continuous	$I_C$	6	A
Base Current — Continuous	$I_B$	1	A
Total Power Dissipation @ $T_A = 25^\circ\text{C}$ @ $T_C = 25^\circ\text{C}$	$P_D$ $P_D$	2.0 25	Watts
Operating and Storage Junction Temperature Range	$T_J, T_{STG}$	-55 to +150	$^\circ\text{C}$

### thermal characteristics

Maximum Lead Temperature for Soldering Purposes: 1/8" from Case for 5 Seconds	$T_L$	260	$^\circ\text{C}$
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electrical characteristics ( $T_A = 25^\circ\text{C}$ ) (unless otherwise specified)

CHARACTERISTIC	SYMBOL	MIN	TYP	MAX	UNIT
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off characteristics

Collector-Emitter Sustaining Voltage ( $I_C = 0.5\text{A}$ , $L = 40\text{mH}$ )	$V_{CE(sus)}$	250	—	—	Volts
Collector Cutoff Current ( $V_{CB} = 300\text{V}$ )	$I_{CBO}$	—	—	0.5	mA
Emitter Cutoff Current ( $V_{EB} = 5\text{V}$ )	$I_{EBO}$	—	—	0.5	mA

second breakdown

Second Breakdown with Base Forward Biased	FBSOA	SEE FIGURE 4
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on characteristics

DC Current Gain ( $I_C = 2\text{A}$ , $V_{CE} = 2\text{V}$ ) ( $I_C = 4\text{A}$ , $V_{CE} = 2\text{V}$ )	$h_{FE}$	2000 200	— —	— —	—
Collector-Emitter Saturation Voltage ( $I_C = 4\text{A}$ , $I_B = 0.04\text{A}$ )	$V_{CE(sat)}$	—	—	2.0	Volts
Base-Emitter Saturation Voltage ( $I_C = 4\text{A}$ , $I_B = 0.04\text{A}$ )	$V_{BE(sat)}$	—	—	2.5	Volts

switching characteristics

Turn-on Time	$V_{CC} = 100\text{V}$ $I_{B1} = I_{B2} = 0.04\text{A}$ Duty Cycle $\leq 1\%$	$t_{on}$	—	1	—	$\mu\text{s}$
Storage Time		$t_{stg}$	—	8	—	
Fall Time		$t_f$	—	5	—	

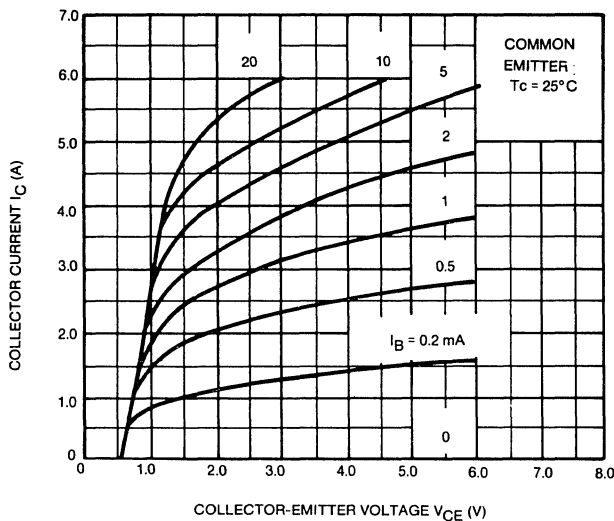


FIG. 1  $I_C - V_{CE}$

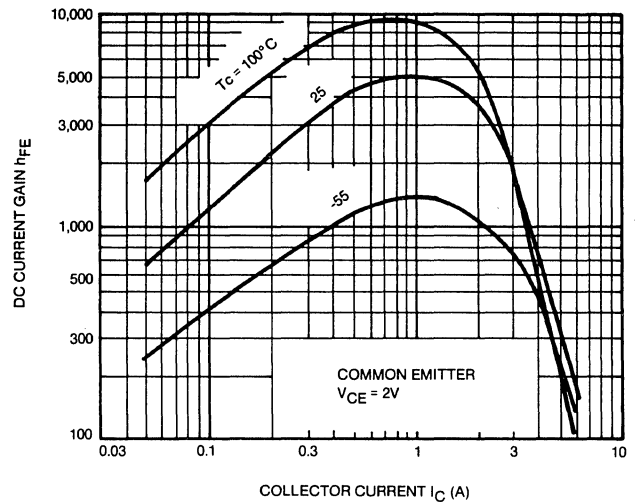


FIG. 2  $h_{FE} - I_C$

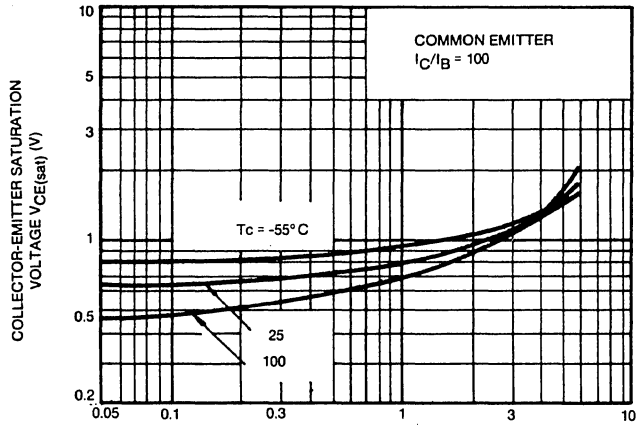


FIG. 3  $V_{CE(sat)} - I_C$

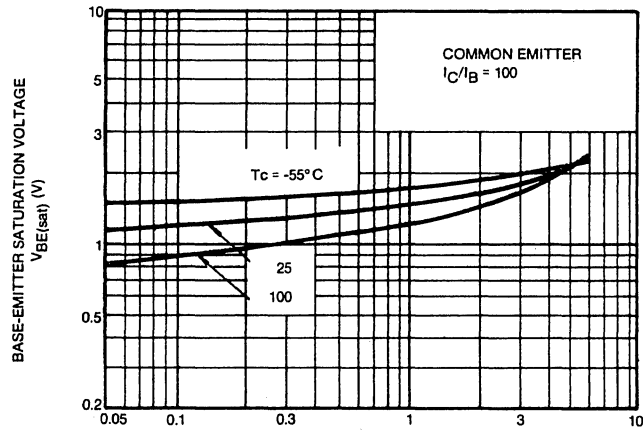


FIG. 5  $V_{BE(sat)} - I_C$

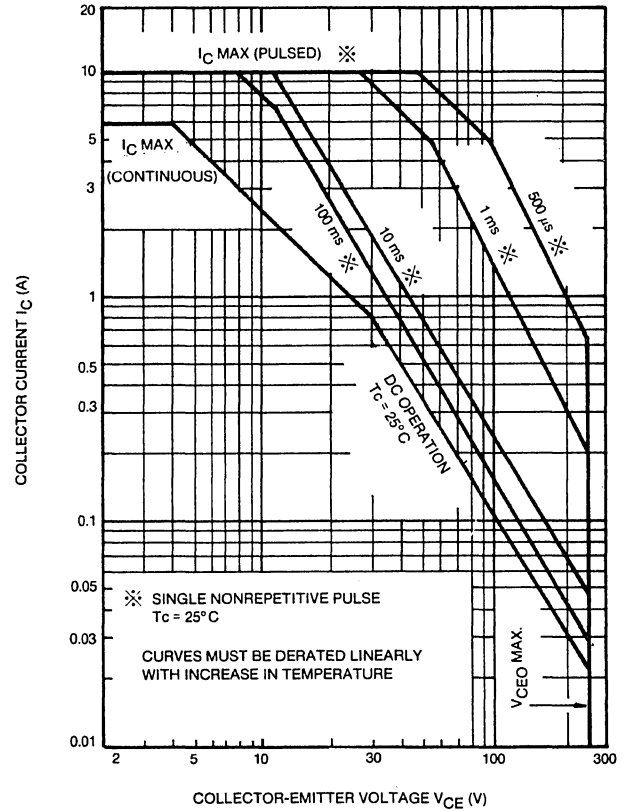


FIG. 4 SAFE OPERATING AREA